



Data Sheet

Single N-Channel 60V 4.8mOhm 75NC 96W PowerTrench SMT Mosfet - POWER 56-8

Manufacturers ON Semiconductor, LLC

Package/Case QFN8

Product Type Transistors

RoHS Green



Images are for reference only

Lifecycle

Please submit RFQ for FDMS86540 or Fmail to us: sales@ovaga.com We will contact you in 12 hours.

<u>RFQ</u>

## **General Description**

This N-Channel MOSFET has been designed specifically to improve the overall efficiency and to minimize switch node ringing of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low RDS(on), fast switching speed and body diode reverse recovery performance.

**Features** Application

Max = 10 V,>

Max = 8 V,>

Advanced package and silicon combination for low rDS(on) and high efficiency

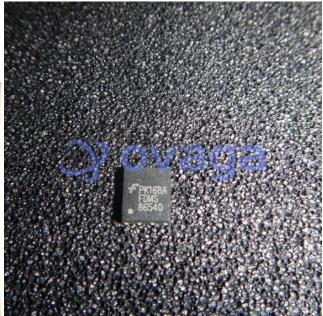
Next generation enhanced body diode technology, engineered for soft recovery

MSL1 robust package design

100% UIL tested

RoHS Compliant





## **Related Products**



**FDC645N** 

ON Semiconductor, LLC SSOT-6



**FDC6305N** 

ON Semiconductor, LLC SSOT-6



**FDD8647L** 

ON Semiconductor, LLC TO-252-3



FDD5N50NZTM

ON Semiconductor, LLC TO-252



FDC637BNZ

ON Semiconductor, LLC SSOT-6



**FDC602P** 

ON Semiconductor, LLC SOT163



**FDB070AN06A0** 

ON Semiconductor, LLC TO-263



**FDD3670** 

ON Semiconductor, LLC TO-252AA